



ZXTP19040CGQ

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEO} > -40V
- I_C = -3A High Continuous Collector Current
- I_{CM} = -5A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(SAT)} < -200mV @ -1.0A
- Lead-Free Finish & RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

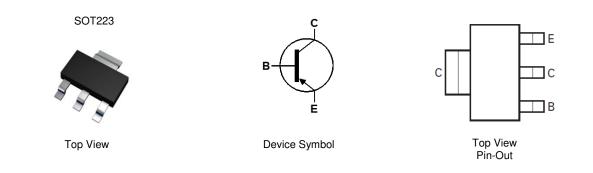
-40V PNP LOW VCESAT TRANSISTOR IN SOT223

Applications

- DC to DC Conversion
- Supply Line Switching
- Low Dropout Regulation
- LCD Backlighting

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP19040CGQ-7	Automotive	TP19040C	7	12	1,000

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

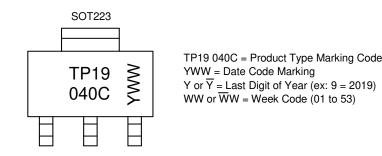
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:





ZXTP19040CGQ

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	lc	-3	A
Peak Pulse Collector Current	I _{CM}	-5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	1.2	W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	104	°C /W
Power Dissipation	(Note 7)	PD	2	W
Thermal Resistance, Junction to Ambient	(Note 7)	R _{θJA}	62.5	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 8)

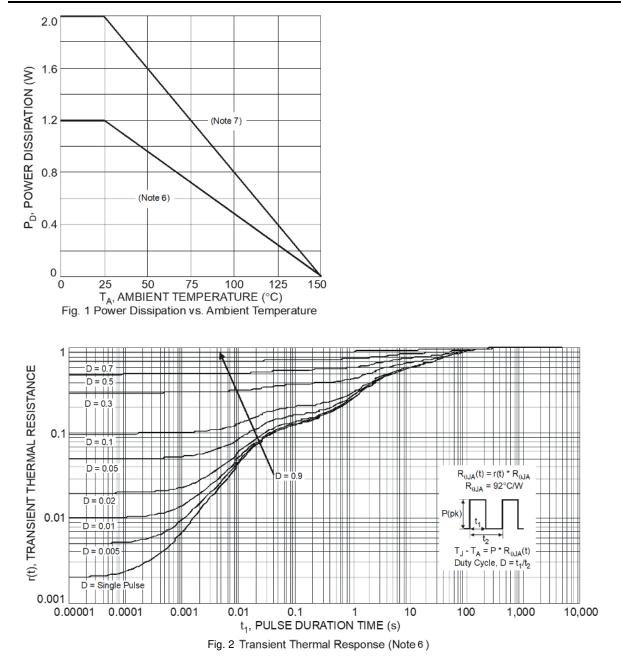
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

Device mounted on FR-4 PCB with minimum recommended pad layout.
 Device mounted on FR-4 PCB using 2oz copper and 25mm x 25mm pad layout.
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





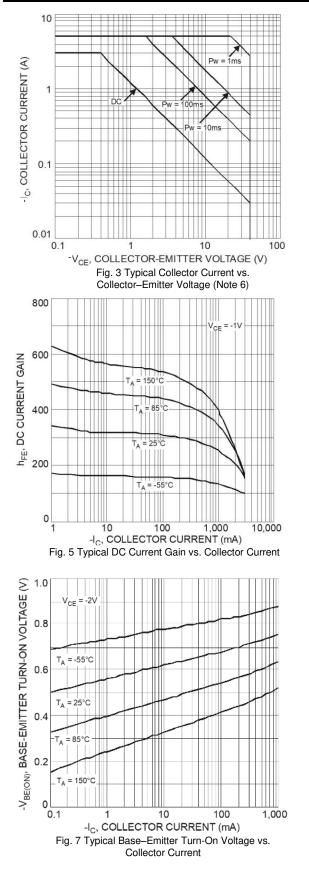
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

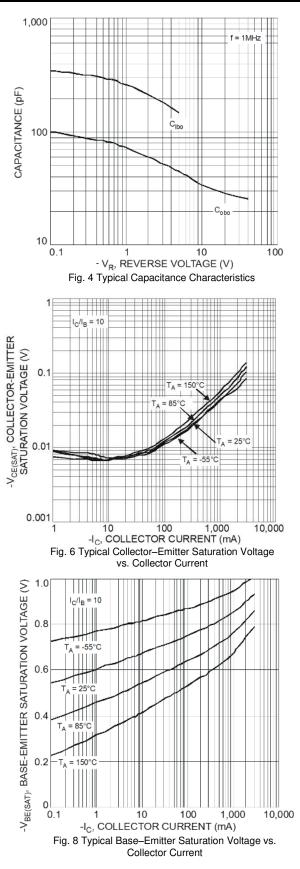
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Conditions	
OFF CHARACTERISTICS (Note 9)	0,		• 76		•		
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_		V	I _C = -100μA	
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40	_		V	$I_{\rm C} = -10 {\rm mA}$	
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	—	—	V	I _E = -50μA	
Collector-Base Cutoff Current		_	_	-100	nA	$V_{CB} = -40V, I_E = 0$	
Collector-Base Cuton Current	I _{CBO}	_	_	-50	μA	$V_{CB} = -40V, I_E = 0, T_A = +150^{\circ}C$	
Emitter-Base Cutoff Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -6V, I_{C} = 0$	
ON CHARACTERISTICS (Note 9)							
		220	—			$V_{CE} = -1V, I_{C} = -0.5A$	
DC Current Gain	h _{FE}	200	_	400		$V_{CE} = -1V, I_{C} = -1A$	
		100	—			$V_{CE} = -1V, I_{C} = -3A$	
		—	—	-150		$I_{C} = -0.5A, I_{B} = -5mA$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		—	-200	mV	$I_{C} = -1A, I_{B} = -10mA$	
			—	-500		$I_{C} = -3A, I_{B} = -0.3A$	
Base-Emitter Saturation Voltage	V _{BE(SAT)}		—	-1.0	V	$I_{C} = -1A, I_{B} = -0.1A$	
Base-Emitter Turn-On Voltage	V _{BE(ON)}	—	_	-1.0	V	$V_{CE} = -2V, I_{C} = -1A$	
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency	f⊤		150	—	MHz	$V_{CE} = -10V, I_{C} = -100mA,$ f = 100MHz	
Output Capacitance	C _{obo}	_	35	_	pF	$V_{CB} = -10V, f = 1MHz$	
Input Capacitance	Cibo	—	150		pF	$V_{CB} = -5V$, f = 1MHz	
SWITCHING CHARACTERISTICS							
Turn-On Time	t _{ON}		53		ns	$V_{CC} = -10V$, $I_{C} = -2A$,	
Delay Time	tD	_	12	—	ns	$V_{CC} = -10V, I_C = -2A,$ $I_{B1} = -200mA$	
Rise Time	t _R	—	41		ns		
Turn-Off Time	toff	_	180		ns	101/1- 20	
Storage Time	ts	_	146		ns	V _{CC} = -10V, I _C = -2A, I _{B1} = -I _{B2} = -200mA	
Fall Time	t _F	_	34	_	ns	$_{1B1} ={1B2} = -20011A$	

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



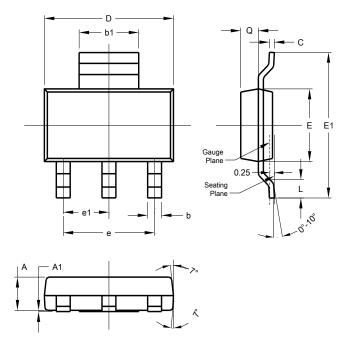




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

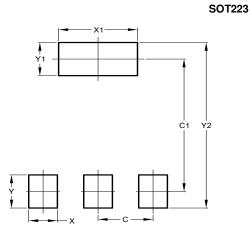
SOT223



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

t version.

ZXTP19040CGQ Datasheet Number: DS40677 Rev. 1 - 2



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2019, Diodes Incorporated

www.diodes.com